

EL32D1EEB2K-125.000M [Click part number to visit Part Number Details page](#)

REGULATORY COMPLIANCE (Data Sheet downloaded on Oct 29, 2016)



◀ Click badges to download compliance docs

Regulatory Compliance standards are subject to updates by governing bodies. Click the badges to download the latest compliance docs for this part number directly from Ecliptek.



ITEM DESCRIPTION

Voltage Controlled Quartz Crystal Clock Oscillators VCXO LVDS (DS) 3.3Vdc 6 Pad 5.0mm x 7.0mm Ceramic Surface Mount (SMD) 125.000MHz ± 25 ppm Maximum over 0°C to +70°C ± 75 ppm Minimum 15% Maximum

ELECTRICAL SPECIFICATIONS

Nominal Frequency	125.000MHz
Frequency Tolerance/Stability	± 25 ppm Maximum over 0°C to +70°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, Shock, and Vibration.)
Supply Voltage	3.3Vdc $\pm 5\%$
Input Current	80mA Maximum
Output Voltage Logic High (Voh)	1.43Vdc Typical, 1.6Vdc Maximum
Output Voltage Logic Low (Vol)	1.1Vdc Typical, 0.9Vdc Minimum
Vdd Magnitude Change (dVod)	-50mV Minimum, +50mV Maximum
Differential Output Voltage (Vod)	247mV Minimum, 355mV Typical, 454mV Maximum
Offset Voltage (Vos)	1.125V Minimum, 1.20V Typical, 1.375V Maximum
Rise/Fall Time	1nSec Maximum (Measured over 20% to 80% of waveform)
Duty Cycle	50 ± 5 (%) (Measured at 50% of waveform)
Offset Voltage Magnitude Change (dVos)	25mV Maximum
Load Drive Capability	100 Ohms (Between Output and Complementary Output)
Output Logic Type	LVDS
Control Voltage	1.65Vdc ± 1.65 Vdc (Test Conditions for Frequency Deviation)
Control Voltage Range	0.0Vdc to Vdd +0.5Vdc
Frequency Deviation	± 75 ppm Minimum (Inclusive of Operating Temperature Range, Supply Voltage, and Load)
Linearity	15% Maximum
Transfer Function	Positive Transfer Characteristic
Modulation Bandwidth	10kHz Minimum (Measured at -3dB with Control Voltage of +1.65Vdc)
Input Impedance	50kOhms Typical
Phase Noise	-55dBc/Hz at offset of 10Hz, -90dBc/Hz at offset of 100Hz, -120dBc/Hz at offset of 1kHz, -140dBc/Hz at offset of 10kHz, -145dBc/Hz at offset of 100kHz, -148dBc/Hz at offset of 1MHz (All Values are Typical)
Logic Control / Additional Output	Tri-State (Enable High) / Complementary Output
Tri-State Input Voltage (Vih and Vil)	Vih of 70% of Vdd Minimum or No Connect to Enable Output and Complementary Output, Vil of 30% of Vdd Maximum to Disable (High Impedance) Output and Complementary Output
RMS Phase Jitter	0.4pSec Typical, 1pSec Maximum (Fj=12kHz to 20MHz; Random)
Accumulated Period Jitter (tacc)	4pSec Typical, 5pSec Maximum Sigma of Total Jitter Distribution
Period Jitter (trj)	3pSec Typical, 5pSec Maximum Sigma of Random Jitter
Period Jitter (trms)	3pSec Typical, 5pSec Maximum Sigma of Total Jitter Distribution
Period Jitter (tdj)	4pSec Typical, 10pSec Maximum Deterministic Jitter
Period Jitter (tp-p)	27pSec Typical, 40pSec Maximum Peak to Peak of Jitter Distribution
Start Up Time	10mSec Maximum
Storage Temperature Range	-55°C to +125°C

EL32D1EEB2K-125.000M

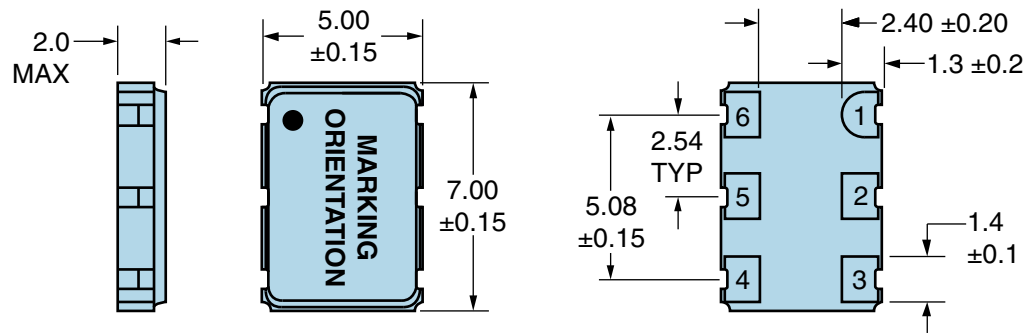
[Click part number to visit Part Number Details page](#)

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS	
Fine Leak Test	MIL-STD-883, Method 1014 Condition A
Gross Leak Test	MIL-STD-883, Method 1014 Condition C
Mechanical Shock	MIL-STD-202, Method 213 Condition C
Resistance to Soldering Heat	MIL-STD-202, Method 210
Resistance to Solvents	MIL-STD-202, Method 215
Solderability	MIL-STD-883, Method 2003
Temperature Cycling	MIL-STD-883, Method 1010
Vibration	MIL-STD-883, Method 2007 Condition A

EL32D1EEB2K-125.000M

[Click part number to visit Part Number Details page](#)

MECHANICAL DIMENSIONS (all dimensions in millimeters)

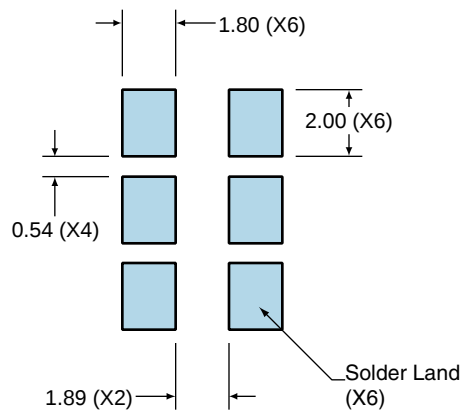


PIN	CONNECTION
1	Control Voltage
2	Tri-State
3	Case/Ground
4	Output
5	Complementary Output
6	Supply Voltage

LINE	MARKING
1	ECLIPTEK
2	125.00M
3	XXXXXX XXXXXX=Ecliptek Manufacturing Identifier

Suggested Solder Pad Layout

All Dimensions in Millimeters

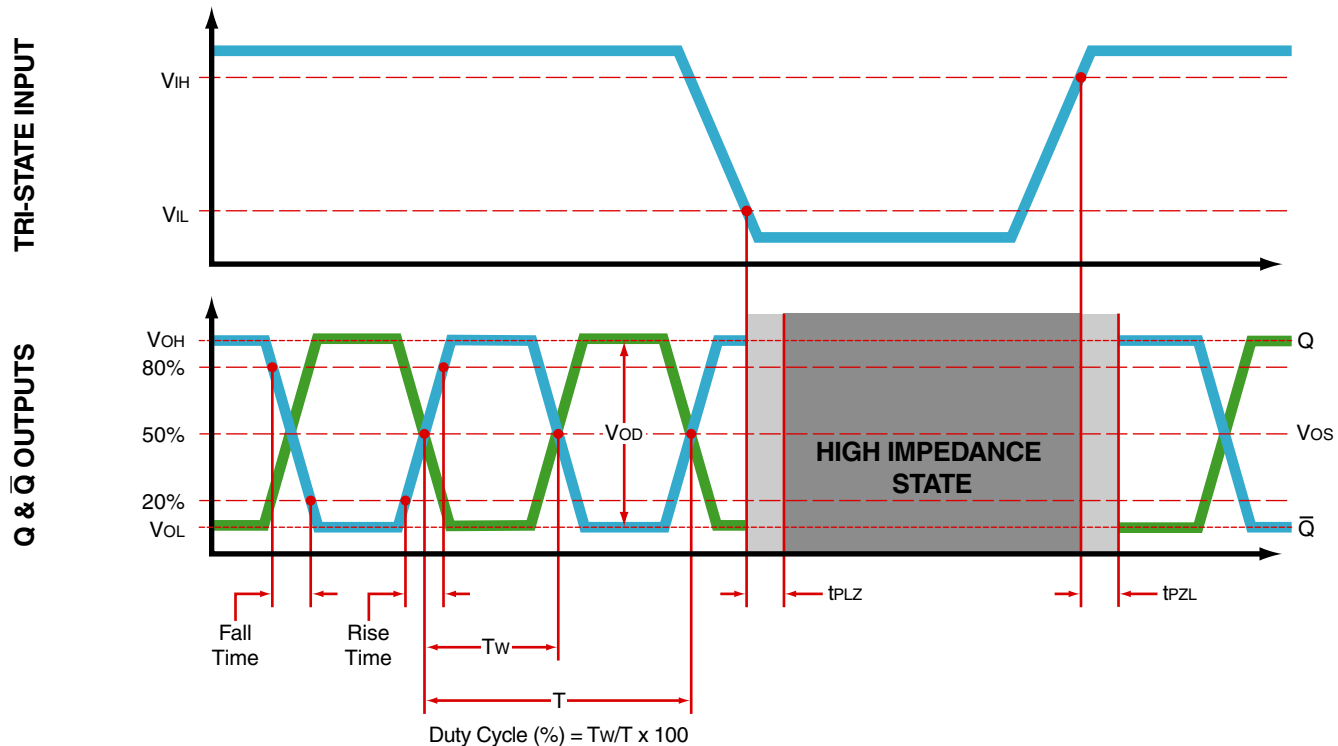


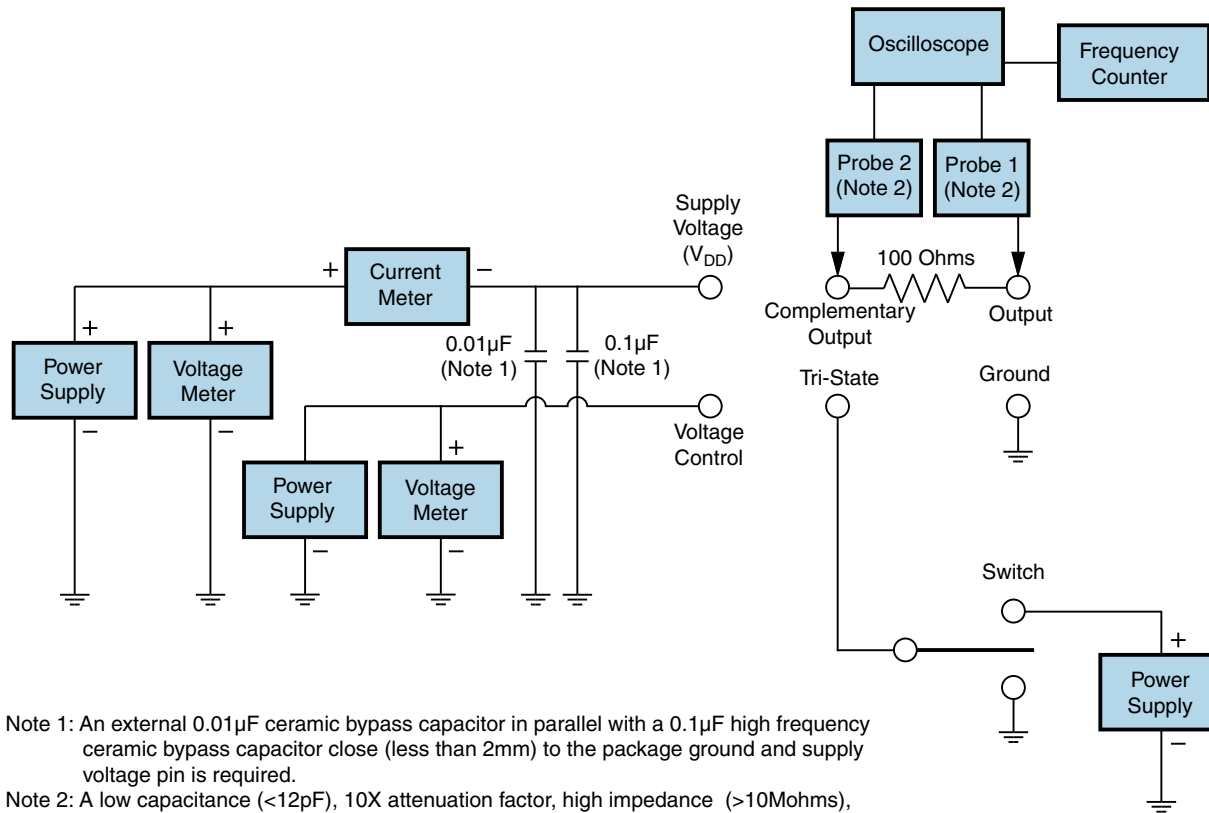
All Tolerances are ±0.1

EL32D1EEB2K-125.000M

[Click part number to visit Part Number Details page](#)

OUTPUT WAVEFORM & TIMING DIAGRAM



EL32D1EEB2K-125.000M [Click part number to visit Part Number Details page](#)**Test Circuit for Tri-State and Complementary Output**

Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less than 2mm) to the package ground and supply voltage pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>500MHz) passive probe is recommended.

Note 3: Test circuit PCB traces need to be designed for a characteristic line impedance of 50 ohms.

EL32D1EEB2K-125.000M [Click part number to visit Part Number Details page](#)

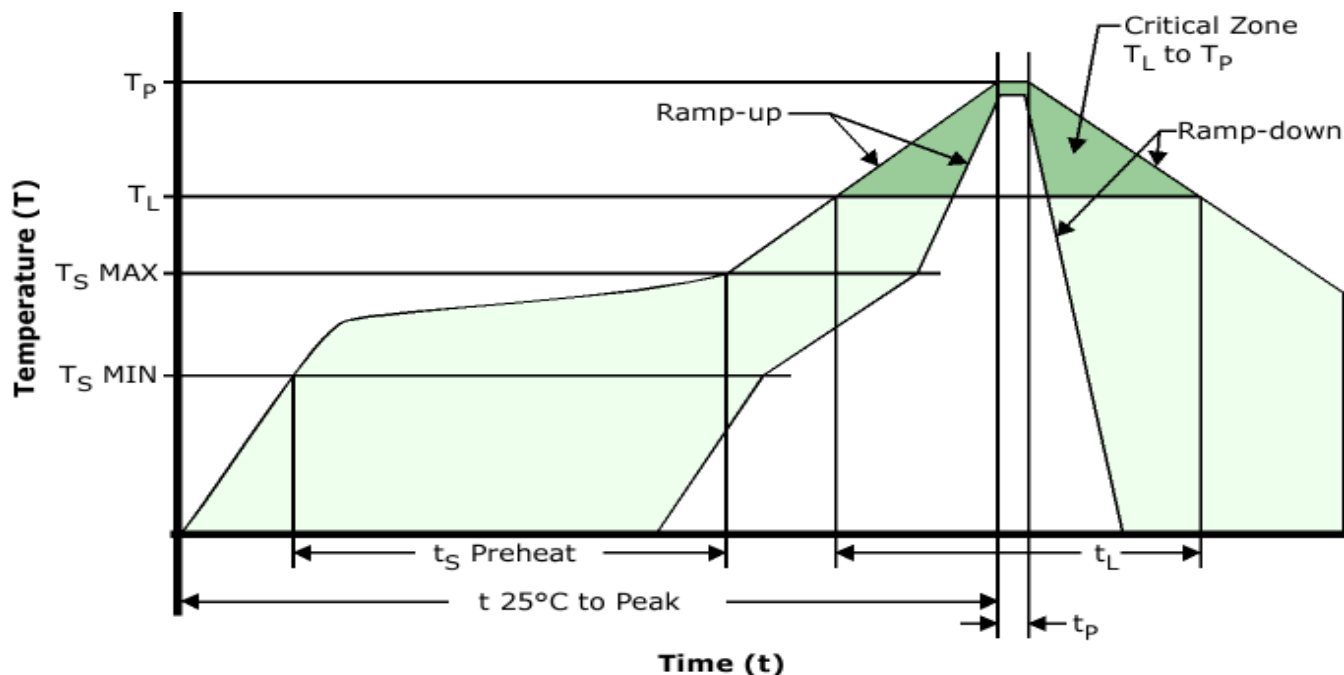


Recommended Solder Reflow Methods



High Temperature Infrared/Convection

Ts MAX to Tl (Ramp-up Rate)	3°C/Second Maximum
Preheat	
- Temperature Minimum (Ts MIN)	150°C
- Temperature Typical (Ts TYP)	175°C
- Temperature Maximum (Ts MAX)	200°C
- Time (ts MIN)	60 - 180 Seconds
Ramp-up Rate (Tl to Tp)	3°C/Second Maximum
Time Maintained Above:	
- Temperature (Tl)	217°C
- Time (tL)	60 - 150 Seconds
Peak Temperature (Tp)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (Tp Target)	250°C +0/-5°C
Time within 5°C of actual peak (tp)	20 - 40 Seconds
Ramp-down Rate	6°C/Second Maximum
Time 25°C to Peak Temperature (t)	8 Minutes Maximum
Moisture Sensitivity Level	Level 1

EL32D1EEB2K-125.000M [Click part number to visit Part Number Details page](#)**Recommended Solder Reflow Methods****Low Temperature Infrared/Convection 240°C**

T _S MAX to T _L (Ramp-up Rate)	5°C/Second Maximum
---	--------------------

Preheat

- Temperature Minimum (T _S MIN)	N/A
- Temperature Typical (T _S TYP)	150°C
- Temperature Maximum (T _S MAX)	N/A
- Time (t _s MIN)	60 - 120 Seconds

Ramp-up Rate (T _L to T _P)	5°C/Second Maximum
--	--------------------

Time Maintained Above:

- Temperature (T _L)	150°C
- Time (t _L)	200 Seconds Maximum

Peak Temperature (T _P)	240°C Maximum
------------------------------------	---------------

Target Peak Temperature (T _P Target)	240°C Maximum 2 Times / 230°C Maximum 1 Time
---	--

Time within 5°C of actual peak (t _p)	10 Seconds Maximum 2 Times / 80 Seconds Maximum 1 Time
--	--

Ramp-down Rate	5°C/Second Maximum
----------------	--------------------

Time 25°C to Peak Temperature (t)	N/A
-----------------------------------	-----

Moisture Sensitivity Level	Level 1
----------------------------	---------

Low Temperature Manual Soldering

185°C Maximum for 10 Seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 Seconds Maximum, 2 times Maximum.